

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application)	<u>PATENT APPLICATION</u>
)	
Inventor: Jian Chen, et al.)	
)	Art Unit: 2824
Application No.: 10/765,963)	
)	Examiner: Tran, Andrew Q.
Filed Date: January 26, 2004)	
)	Customer No.: 64948
Title: METHOD OF READING NAND MEMORY))	
TO COMPENSATE FOR COUPLING BETWEEN))	
STORAGE ELEMENTS)	

RESPONSE B TO OFFICE ACTION UNDER 37 C.F.R. § 1.116

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Sir:

*Entry denied-
at
09/17/2007*

This RESPONSE B is in reply to the Office Action mailed June 11, 2007.

AMENDMENTS TO THE CLAIMS are reflected in the listing of claims which begin on page 2 of this Response.

AMENDMENTS TO THE ABSTRACT are reflected in the listing of claims which begin on page 6 of this Response.

REMARKS begin on Page 7 of this Response.